
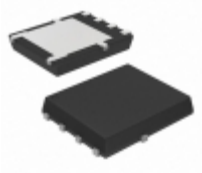
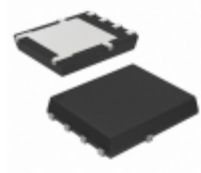
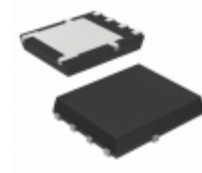
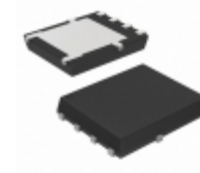

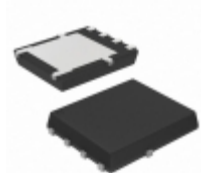
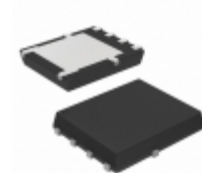

	<h2>NTMFS4707NT1G</h2>
	<p>Hersteller-Teilenummer: NTMFS4707NT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 6.9A SO8FL</p> <p>Datenblätter:  NTMFS4707NT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 8854 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMFS4707NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 6.9A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	8854 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN, 5 Leads
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	1W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	6.9A (Ta)
Rds On (Max) @ Id, Vgs	13 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	735pF @ 24V
Verpackung	Tape & Reel (TR)

NTMFS4707NT1G ist neu im Original, Suche NTMFS4707NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMFS4707NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMFS4707NT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMFS4701NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 7.7A SO8FL</p>	 <p>NTMFS4708NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 7.8A SO8FL</p>	 <p>NTMFS4701NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 7.7A SO8FL</p>	 <p>NTMFS4708NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 7.8A SO8FL</p>
 <p>NTMFS4709NT1G ON NTMFS4709NT1G ON</p>	 <p>NTMFS4122NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9.1A SO8FL</p>	 <p>NTMFS4122NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9.1A SO-8FL</p>	 <p>NTMFS4707NT1G.. O O QFN81500</p>

heiße Teile

Mehr

NTMD6N02R2G	NTMD6N03	NTMD6N03DR2G	NTMD6N03R2	NTMD6N03R2G
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NTMD6P02R2G.	NTMD6P02R2SG	NTMFD4901NF1G	NTMFD4901NFT1G	NTMFD4902NF1G
NTMFD4902NFT1G	NTMFD4C85NT1G	NTMFD4C85NTG	NTMFD4H089NFT1G	NTMFS4108NT1G
NTMFS4108NT3G	NTMFS4119NT3G	NTMFS4120NT1G	NTMFS4121NT1G	NTMFS4701NT1G
NTMFS4708NT1G	NTMFS4709NT1G	NTMFS4709NT3G	NTMFS4744NT1G	NTMFS4821NT1G
NTMFS4823NT1G	NTMFS4833NT1G	NTMFS4834N	NTMFS4834NT1G	NTMFS4835N
NTMFS4835NT1G	NTMFS4837NHT1G	NTMFS4837NHT3G	NTMFS4837NT1G	NTMFS4839NHT1G
NTMFS4841NHT1G	NTMFS4841NHT3G	NTMFS4841NT1G	NTMFS4845NT1G	NTMFS4846
NTMFS4846NT1G	NTMFS4847N	NTMFS4847NAT1G	NTMFS4847NT1G	NTMFS4849NT1G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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